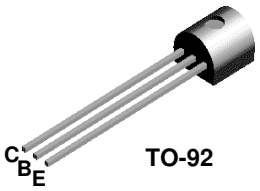
FAIRCHILD
SEMICONDUCTOR®

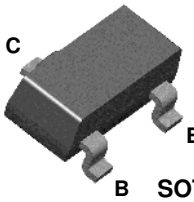
2N5210/MMBT5210

NPN General Purpose Amplifier

This device is designed for low noise, high gain, general purpose amplifier applications at collector currents from 1μA to 50 mA.



TO-92



SOT-23
Mark: 3M

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CEO}	Collector-Emitter Voltage	50	V
V_{CBO}	Collector-Base Voltage	50	V
V_{EBO}	Emitter-Base Voltage	4.5	V
I_C	Collector Current - Continuous	100	mA
T_J, T_{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:
1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics TA = 25°C unless otherwise noted

Symbol	Characteristic	Max.		Units
		2N5210	MMBT5210	
P_D	Total Device Dissipation Derate above 25°C	625 5.0	350 2.8	mW mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3		°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	357	°C/W

NPN General Purpose Amplifier
(continued)

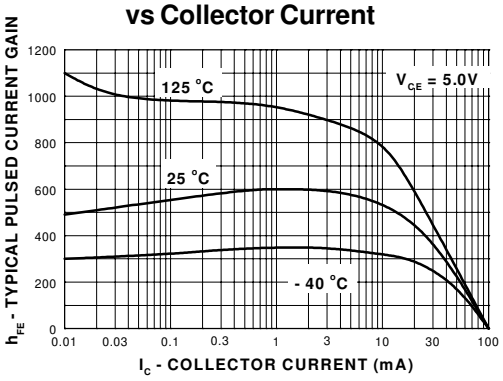
Electrical Characteristics
TA = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Max	Units
OFF CHARACTERISTICS					
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	I_C = 1.0 mA, I_B = 0	50		V
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	I_C = 0.1 mA, I_E = 0	50		V
I_{CBO}	Collector Cutoff Current	V_{CB} = 35 V, I_E = 0		50	nA
I_{EBO}	Emitter Cutoff Current	V_{EB} = 3.0 V, I_C = 0		50	nA
ON CHARACTERISTICS					
h_{FE}	DC Current Gain	I_C = 100 µA, V_{CE} = 5.0 V I_C = 1.0 mA, V_{CE} = 5.0 V I_C = 10 mA, V_{CE} = 5.0 V*	200 250 250	600	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	I_C = 10 mA, I_B = 1.0 mA		0.7	V
$V_{BE(on)}$	Base-Emitter On Voltage	I_C = 1.0 mA, V_{CE} = 5.0 V		0.85	V
SMALL SIGNAL CHARACTERISTICS					
f_T	Current Gain - Bandwidth Product	I_C = 500 µA, V_{CE} = 5.0 V, f= 20 MHz	30		MHz
C_{cb}	Collector-Base Capacitance	V_{CB} = 5.0 V, I_E = 0, f = 100 kHz		4.0	pF
h_{fe}	Small-Signal Current Gain	I_C = 1.0 mA, V_{CE} = 5.0 V, f = 1.0 kHz	250	900	
NF	Noise Figure	I_C = 20 µA, V_{CE} = 5.0 V, R_S = 22 kΩ, f = 10 Hz to 15.7 kHz I_C = 20 µA, V_{CE} = 5.0 V, R_S = 10 kΩ, f = 1.0 kHz		2.0 3.0	dB dB

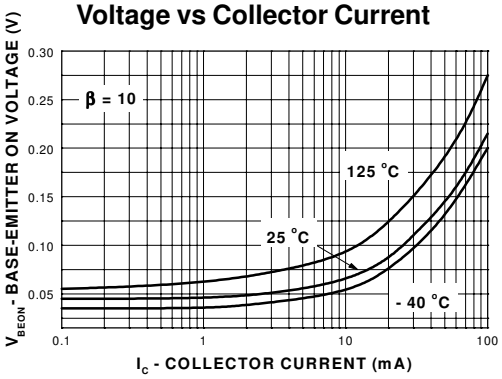
*Pulse Test: Pulse Width ≤ 300 µs, Duty Cycle ≤ 2.0%

Typical Characteristics

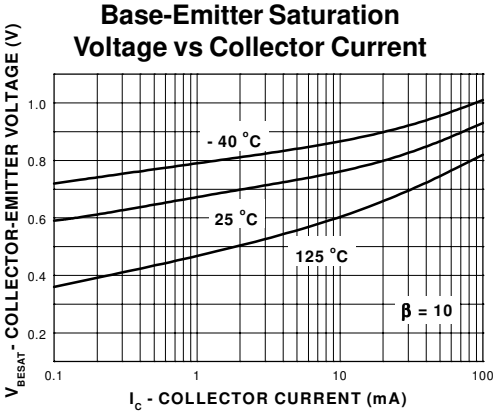
Typical Pulsed Current Gain vs Collector Current



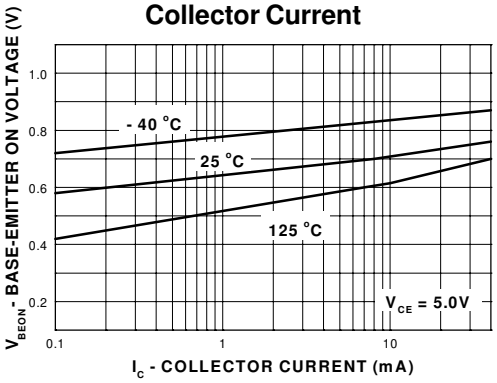
Collector-Emitter Saturation Voltage vs Collector Current



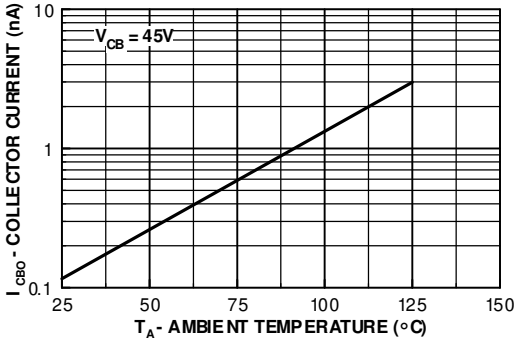
Base-Emitter Saturation Voltage vs Collector Current



Base-Emitter ON Voltage vs Collector Current

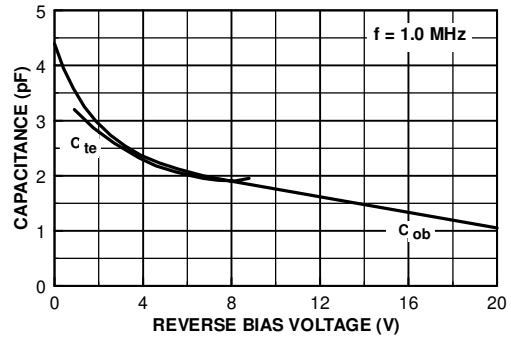


Collector-Cutoff Current vs Ambient Temperature

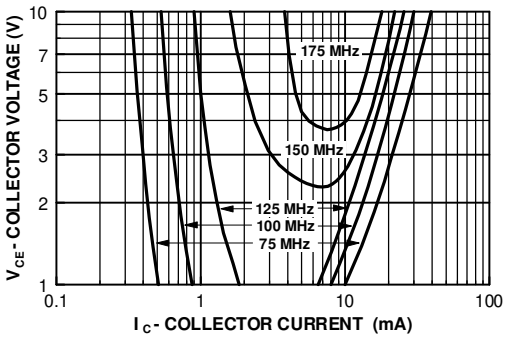


Typical Characteristics (continued)

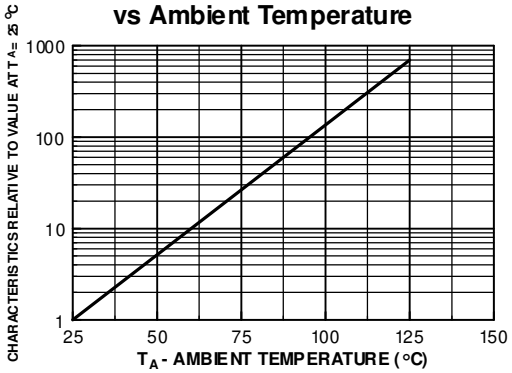
Input and Output Capacitance vs Reverse Bias Voltage



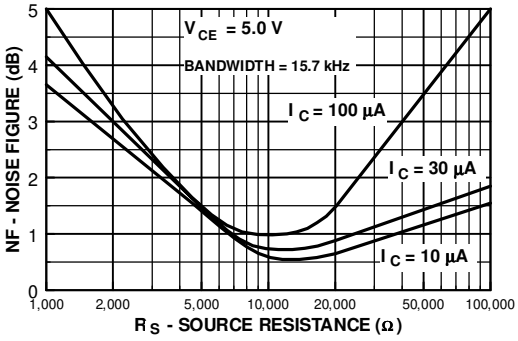
Contours of Constant Gain Bandwidth Product (f_T)



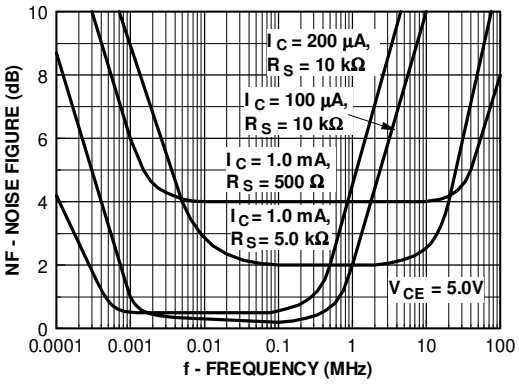
Normalized Collector-Cutoff Current vs Ambient Temperature



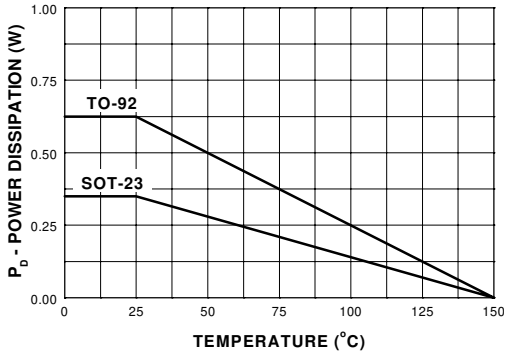
Wideband Noise Frequency vs Source Resistance



Noise Figure vs Frequency

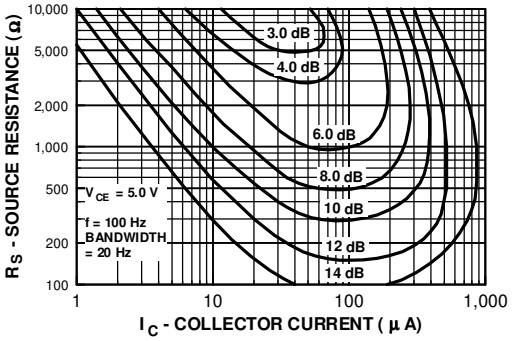


Base-Emitter Saturation Voltage vs Collector Current

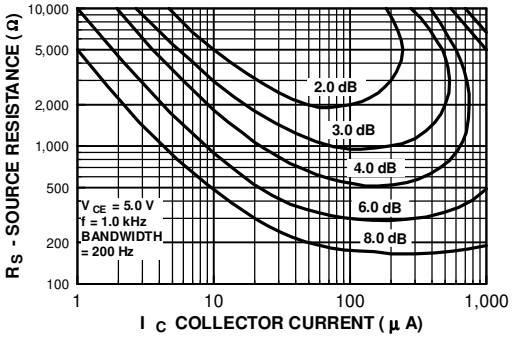


Typical Characteristics (continued)

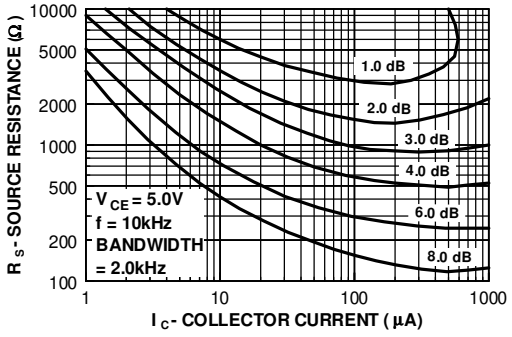
Contours of Constant Narrow Band Noise Figure



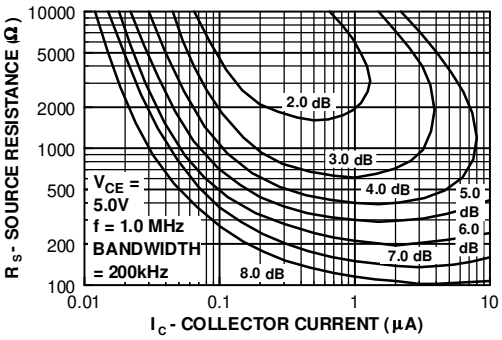
Contours of Constant Narrow Band Noise Figure



Contours of Constant Narrow Band Noise Figure



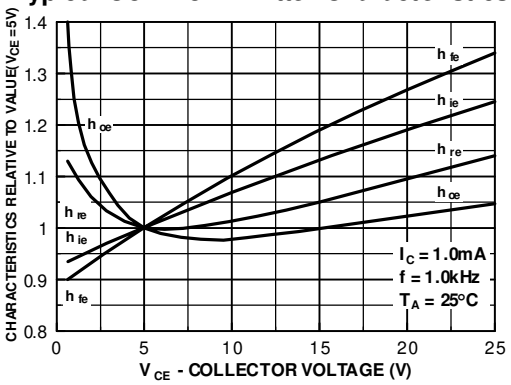
Contours of Constant Narrow Band Noise Figure



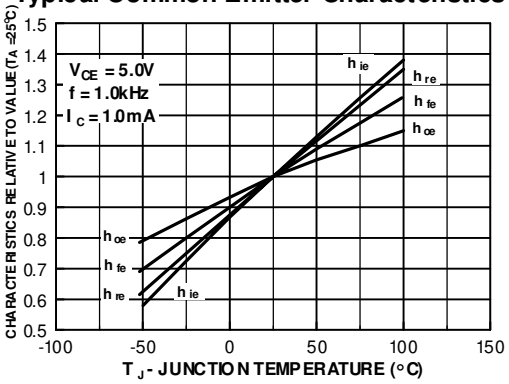
NPN General Purpose Amplifier
(continued)

Typical Common Emitter Characteristics (f = 1.0 kHz)

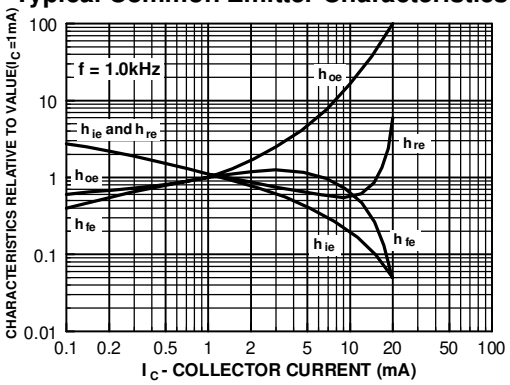
Typical Common Emitter Characteristics



Typical Common Emitter Characteristics



Typical Common Emitter Characteristics



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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.

2N5210

NPN General Purpose Amplifier

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Datasheet

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- Product Change Notices (PCNs)
- Support
- Sales support
- Quality and reliability
- Design center

General description

This device is designed for low noise, high gain, general purpose amplifier applications at collector currents from 1µA to 50 mA.

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Product status/pricing/packaging

BUY

Product	Product status	Pb-free Status	Pricing*	Package type	Leads	Packing method	Package Marking Convention**
2N5210BU	Full Production	Full Production	$0.0238	TO-92	3	BULK	Line 1: 2N Line 2: 5210 Line 3: -&3
2N5210NMBU	Full Production	Full Production	$0.0238	TO-92	3	BULK	N/A
2N5210TA	Full Production	Full Production	$0.0238	TO-92	3	AMMO	Line 1: 2N Line 2: 5210 Line 3: -&3
2N5210TAR	Full Production		$0.0238	TO-92	3	AMMO	Line 1: 2N Line 2: 5210 Line 3: -&3

		Full Production					
2N5210TF	Full Production	Full Production	$0.0238	TO-92	3	TAPE REEL	Line 1: 2N Line 2: 5210 Line 3: -&3
2N5210TFR	Full Production	Full Production	$0.0238	TO-92	3	TAPE REEL	Line 1: 2N Line 2: 5210 Line 3: -&3
2N5210_D81Z	Full Production	Full Production	N/A	TO-92	3	TAPE REEL	Line 1: **$Y** (Fairchild logo) &**Z** (Asm. Plant Code) &**3** (3-Digit Date Code) Line 2: 2N Line 3: 5210
2N5210_J05Z	Full Production	Full Production	N/A	TO-92	3	BULK	Line 1: **$Y** (Fairchild logo) &**Z** (Asm. Plant Code) &**3** (3-Digit Date Code) Line 2: 2N Line 3: 5210

* Fairchild 1,000 piece Budgetary Pricing
** A sample button will appear if the part is available through Fairchild's on-line samples program. If there is no sample button, please contact a Fairchild distributor to obtain samples

Indicates product with Pb-free second-level interconnect. For more information click here.

Package marking information for product 2N5210 is available. Click here for more information .

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Models

Package & leads	Condition	Temperature range	Software version	Revision date
PSPICE				
TO-92-3	Electrical	25°C	N/A	N/A

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Qualification Support

Click on a product for detailed qualification data

Product
2N5210BU
2N5210NMBU
2N5210TA
2N5210TAR
2N5210TF
2N5210TFR
2N5210_D81Z
2N5210_J05Z

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